



Application Specific Discretes A.S.D.™

FIRE LIGHTER CIRCUIT

FEATURES

- Dedicated thyristor structure for capacitance discharge ignition operation
- High pulse current capability 190A @ tp = 10µs
- Fast turn-on operation
- Designed for high ambient temperature (up to 120°C)

BENEFITS

- Space saving thanks to monolithic function integration
- High reliability with planar technology



The FLC01 series has been especially developed for capacitance discharge operation. The main applications are gas lighters or ignitors such as cookers / gas boilers / gas hobs...

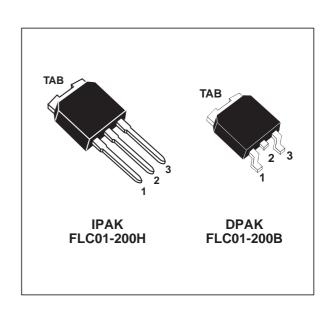
Based on ST's ASD™ technology, it provides a fully integrated function, with high performance and reliability levels, adapted to severe and hot temperature environment.

Th: Thyristor for switching operation.

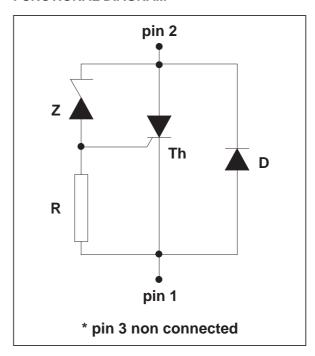
Z: Zener diode to set the threshold voltage.

D: Diode for reverse conduction.

R: $2 k\Omega$ resistor.



FUNCTIONAL DIAGRAM

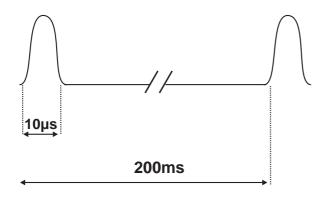


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ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit		
I _{TRM}	Repetitive surge peak on state current for thyristor -30°C ≤ T _{amb} ≤ 120°C				
I _{FRM}	Repetitive surge peak on state current for diode -30°C ≤ T _{amb} ≤ 120°C				
dl/dt	Critical rate of rise time on state current $-30^{\circ}C \le T_{aml}$	120	A/μs		
Tstg Tj	Storage junction temperature range Maximum junction temperature	- 40 to + 150 + 125	°C		
Toper	Operating temperature range	-30 + 120	°C		
TL	Maximum lead temperature for soldering during 10s		260	°C	

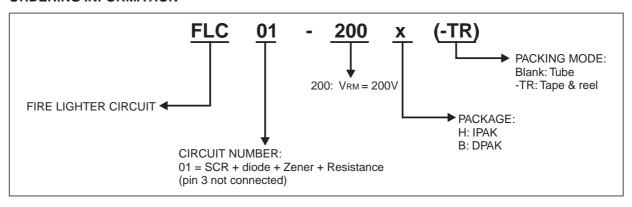
Note 1 : Test current waveform



THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Thermal resistance junction to ambient	100	°C/W

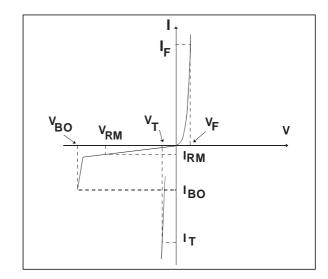
ORDERING INFORMATION



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ELECTRICAL CHARACTERISTICS

Symbol Parameters			
V _{RM}	Stand-off voltage		
V _{BO} Breakover voltage			
V _T	On-state voltage		
V _F	Diode forward voltage drop		
I _{BO}	Breakover current		
I _{RM}	Leakage current		
αΤ	Temperature coefficient for V _{BO}		



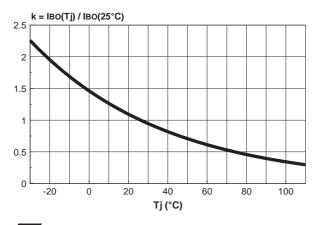
DIODE (D) PARAMETER

Symbol		Test Condition	าร		Value	Unit	
V_{F}	I _F = 2A	tp ≤ 500µs	Tj = 25°C	Max.	1.7	V	

THYRISTOR (Th) and ZENER (Z) PARAMETERS

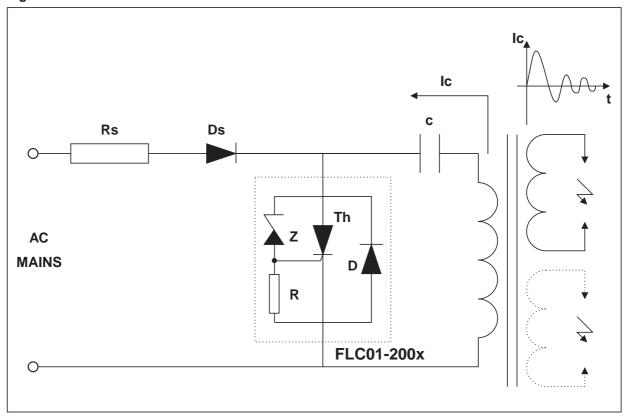
Symbol	Test conditions		Min.	Тур.	Max.	Unit
I_{RM}	V _{RM} = 200 V	Tj = 25°C			1	μΑ
		Tj = 125°C			10	μΑ
V_{BO}	at I _{BO}	Tj = 25°C	206	220	233	V
I _{BO}	at V _{BO}	Tj = 25°C			0.5	mA
V _T	I _T = 2A tp ≤ 500μs	Tj = 25°C			1.7	V
αΤ				0.27		V/°C

Fig. 1: Relative variation of breakover current versus junction temperature.



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Fig. 2: BASIC APPLICATION



The applications of the lighter using the capacitance discharge topology operate in 2 phases:

PHASE 1

The energy coming from the mains is stored into the capacitor C. For that, the AC voltage is rectified by the diode Ds.

PHASE 2

At the end of the phase 1, the voltage across the capacitor C reaches the avalanche threshold of the zener. Then a current flows through the gate of the thyristor Th which fires.

The firing of the thyristor causes an alternating current to flow through the capacitor C.

The positive parts of this current flow through C, Th and the primary of the HV transformer.

The negative parts of the current flow through C, D and the primaty of the HV transformer.

RS RESISTOR CALCULATION

The Rs resistor allows, in addition with the capacitor C, the spark frequency to be adjusted and the current from the mains to be limited. Its value shall allow the thyristor Th to fire even in the worst case. In this case the system must fire with the lower RMS mains voltage value while the breakdown voltage and current of the FLC are at the maximum.

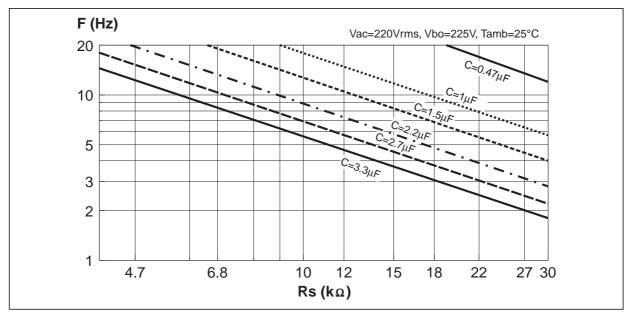
The maximum Rs value is equal to:

$$Rs \max = \frac{(V_{AC} \min.\sqrt{2}) - [V_{BO} \max.(1 + \alpha T.(T_{amb} - 25))]}{k.I_{BO}*}$$

*: see fig 1

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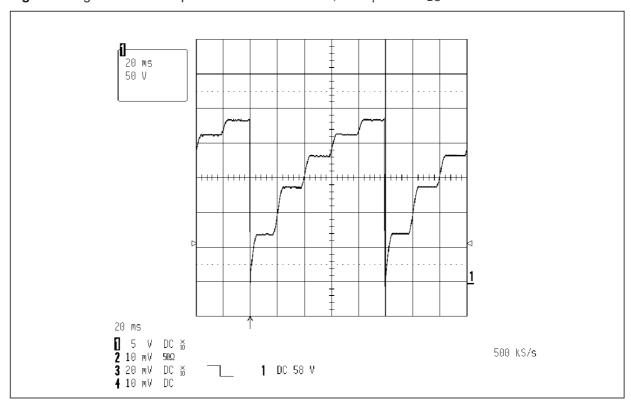
Fig. 3: Spark frequency versus Rs and C



The couple Rs/C can be chosen with the previous curve. Keep in mind the Rs maximum limit for which the system would not work when the AC

mains is minimum. The next curve shows the behavior with Rs=15k Ω and C=1 $\mu F.$

Fig. 4: Voltage across the capacitance with Rs = $15k\Omega$, C = 1μ F and V_{BO} = 225V.

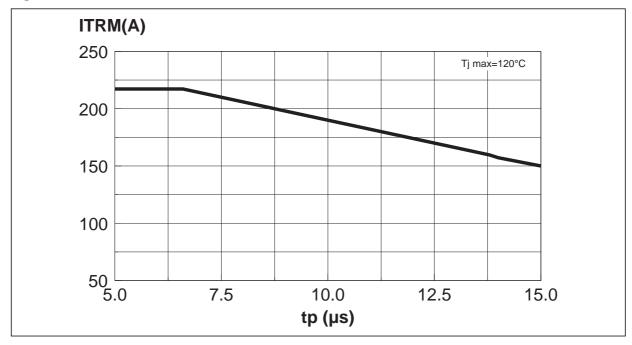


PEAK CURRENT LIMIT

This component is designed to withstand $I_{TRM} = 190 A$ for a pulse duration of $10 \mu s$ for an

ambient temperature of 120°C in repetitive surge. The curve of peak current versus the pulse duration allows us to verify if the application is within the FLC operating limit.

Fig. 5: Peak current limit

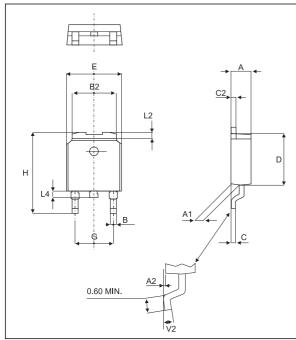


POWER LOSSES (For 10µs, see note 1)

To evaluate the power losses, please use the following equations:

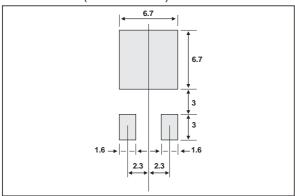
For the thyristor : $P = 1.18 \times I_{T(AV)} + 0.035 I_{T(RMS)}^2$ For the diode : $P = 0.67 \times I_{F(AV)} + 0.106 I_{F(RMS)}^2$

PACKAGE MECHANICAL DATA DPAK



REF.	Millim	neters	Inches		
	Min.	Max	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

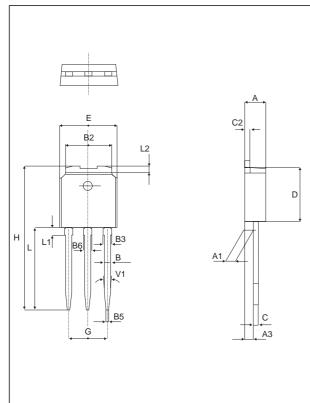
FOOTPRINT (in millimeters)



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PACKAGE MECHANICAL DATA

IPAK



	DIMENSIONS						
REF.	Mi	illimete	rs		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	2.2		2.4	0.086		0.094	
A1	0.9		1.1	0.035		0.043	
А3	0.7		1.3	0.027		0.051	
В	0.64		0.9	0.025		0.035	
B2	5.2		5.4	0.204		0.212	
В3			0.85			0.033	
B5		0.3			0.035		
B6			0.95			0.037	
С	0.45		0.6	0.017		0.023	
C2	0.48		0.6	0.019		0.023	
D	6		6.2	0.236		0.244	
Е	6.4		6.6	0.252		0.260	
G	4.4		4.6	0.173		0.181	
Н	15.9		16.3	0.626		0.641	
L	9		9.4	0.354		0.370	
L1	0.8		1.2	0.031		0.047	
L2		0.8	1		0.031	0.039	
V1		10°			10°		

OTHER INFORMATION

Туре	Marking	Package	Weight	Base qty	Delivery mode
FLC01-200H	FLC01-200H	IPAK	0.40 g	75	Tube
FLC01-200B	FLC01-200B	DPAK	0.40 g	75	Tube
FLC01-200B-TR	FLC01-200B	DPAK	0.40 g	2500	Tape & reel

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